# Sensor R&D at Brown

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We can measure CV/IV curves at temperatures as low as -30° C



### Charge collection measurement setup



#### Measurements can be taken at temperatures as low as -25° C

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### Setup for long-term measurements

- MSSD sensor
- Sr-90 source (37 MBq)
- ARC station to read out sensor

- bias voltage 700 V
- temperature -20° C
- dry atmosphere
- source remains in same place



# Signals

- seed strip
  - >5 \* noise
  - shoulder from hits that straddle two strips
  - hard to fit → use median
- cluster
  - add up signal in 5 strips
  - centered on seed strip



# Region 5

- strip pitch 120  $\mu$ m
- implant width 28  $\mu$ m
- Irradiated sensor (10<sup>15</sup>/cm<sup>2</sup>)



# **Operational parameters**



### temperature

- target is -20°C
- keep above dew point to prevent condensation

### bias voltage

- target is -700 V
- current limit is 1.5 mA
- when temperature increases current increases and voltage may have to drop
- periodic measurements
  - red lines

### Measurement of unirradiated sensor



→ measurements at -10° C

We have now solved this problem and can maintain dewpoint stable < -20° C → Redoing measurements

### Hamburg measurements

Unirradiated p-spray sensor Measured @ 600 V and -20°C Irradiated p-spray sensor Fluence =  $1.5 \times 10^{14}$  p +  $6 \times 10^{14}$  n Measured @ 1000 V and -20°C



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# Scanning-TCT setup



#### Conectivity:

- LV power supply
- Temperature controller
- HV source
- Oscilloscope

Different detector mounts available (Edge-TCT, Surface-TCT)

#### Mechanical properties:

- ~>1 µm resolution in x-y-z
- movement range 5 cm (focus range of Red/Infrared)
- table load 2 kg
- USB controlled positioning

#### **Optical properties:**

- spot size ~6 μm (red), ~10 μm (IR-1064 nm)
- laser fiber coupled
- Intensity variation neutral density filter (optional), shutter, reduction of laser pulse width

#### Laser:

- 1064 nm (200 mW in CV)
- From few mip to few 100 mip
- > ~350-4000 ps
- USB controlled pattern/width/freq

#### Amplfiers:

- 52 dB. Flat for <0.3 MHz >2000 MHz
- > 6-15V, 50  $\Omega$  termination,
- Coupled to bias-T

#### Temperature control:

- Water cooled Peltier element
- dry air/gas inlet
- Pt-100 connected to T controller

Measurements can be taken at temperatures as low as -30° C

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### Schematic of TCT setup



### Focus measurement



### Focus measurement



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### Near term plans

- Irradiation time at LANSCE
  - October 20/21 (?)
  - Plan to irradiate pixel sensors
  - Any other samples?
- Characterizations
  - 19 neutron+proton irradiated HPK sensors
  - Fluences = 1.5×10<sup>15</sup> p(23 MeV) + 6×10<sup>14</sup> n (R=15 cm)
  - Different materials FZ/FTH/MCz and p-type/p-type
  - Thickness = 200 μm
  - Have been measured before irradiation and after proton irradiation
  - Measure CV/IV, TCT after neutron irradiation and compare